

Product data sheet

## 1. Product profile

### 1.1 General description

Two planar PIN diodes in common cathode configuration in a SOT323 small plastic SMD package.

#### 1.2 Features and benefits

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- Low series inductance
- For applications up to 3 GHz
- AEC-Q101 qualified

### 1.3 Applications

RF attenuators and switches

## 2. Pinning information

Table 1. Discrete pinning

Pin	Description	Simplified outline	Symbol
1	anode (a1)		
2	anode (a2)	3	3
3	common cathode	1 2	1 2 sym136
		top view	

# 3. Ordering information

Table 2. Ordering information

Type number	Package				
	Name	Description	Version		
BAP64-05W	-	plastic surface-mounted package; 3 leads	SOT323		



## 4. Marking

Table 3. Marking

Type number	Marking	Description
BAP64-05W	P64-05W 5W*	
		* = W : made in China

#### Table 4. Marking

Type number	Marking code
BAP64-05W	5W-

# 5. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Values are specified per diode.

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	reverse voltage		-	100	V
I <sub>F</sub>	forward current		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> = 90 °C	-	240	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

## 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		250	K/W

## 7. Characteristics

#### Table 7. Characteristics

Values are specified per diode;  $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{F}$	forward voltage	$I_F = 50 \text{ mA}$	-	0.95	1.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 175 V	-	-	10	μΑ
		V <sub>R</sub> = 20 V	-	-	1	μΑ
C <sub>d</sub>	diode capacitance	see Figure 1; f = 1 MHz;				
		V <sub>R</sub> = 0 V	-	0.52	-	pF
		V <sub>R</sub> = 1 V	-	0.37	-	pF
		V <sub>R</sub> = 20 V	-	0.23	0.35	pF

 Table 7.
 Characteristics ...continued

Values are specified per diode;  $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
r <sub>D</sub>	diode forward resistance	see <u>Figure 2</u> ; f = 100 MHz; [1]				
		I <sub>F</sub> = 0.5 mA	-	20	40	Ω
		I <sub>F</sub> = 1 mA	-	10	20	Ω
		I <sub>F</sub> = 10 mA	-	2.0	3.8	Ω
		I <sub>F</sub> = 100 mA	-	0.7	1.35	Ω
τ∟	charge carrier life time	when switched from $I_F$ = 10 mA to $I_R$ = 6 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 3 mA	-	1.55	-	μS
L <sub>S</sub>	series inductance		-	1.2	-	nΗ

[1] Guaranteed on AQL basis: inspection level S4, AQL 1.0.

### 7.1 Graphical data

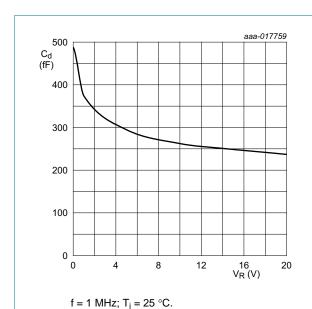
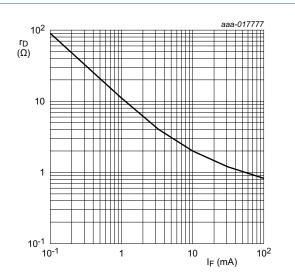
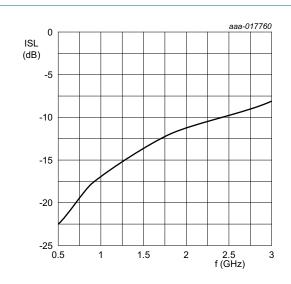


Fig 1. Diode capacitance as a function of reverse voltage; typical values



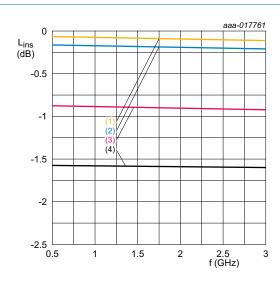
f = 100 MHz;  $T_i = 25 \,^{\circ}\text{C}$ .

Fig 2. Forward resistance as a function of forward current; typical values



 $T_{amb} = 25 \, ^{\circ}C$ 

Diode zero biased and inserted in series with a 50  $\Omega$  stripline circuit

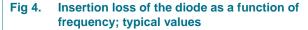


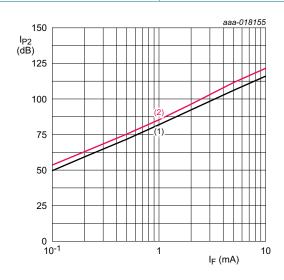
T<sub>amb</sub> = 25 °C

- (1)  $I_F = 100 \text{ mA}$
- (2)  $I_F = 10 \text{ mA}$
- (3)  $I_F = 1 \text{ mA}$
- (4)  $I_F = 0.5 \text{ mA}$

Diode inserted in series with a 50  $\Omega$  stripline circuit and biased via the analyzer Tee network

Fig 3. Isolation of the diode as a function of frequency; typical values





T<sub>amb</sub> = 25 °C

- (1) f = 900 MHz
- (2) f = 1800 MHz

Fig 5. Second-order intercept point as a function of forward current; typical values

## 8. Package outline

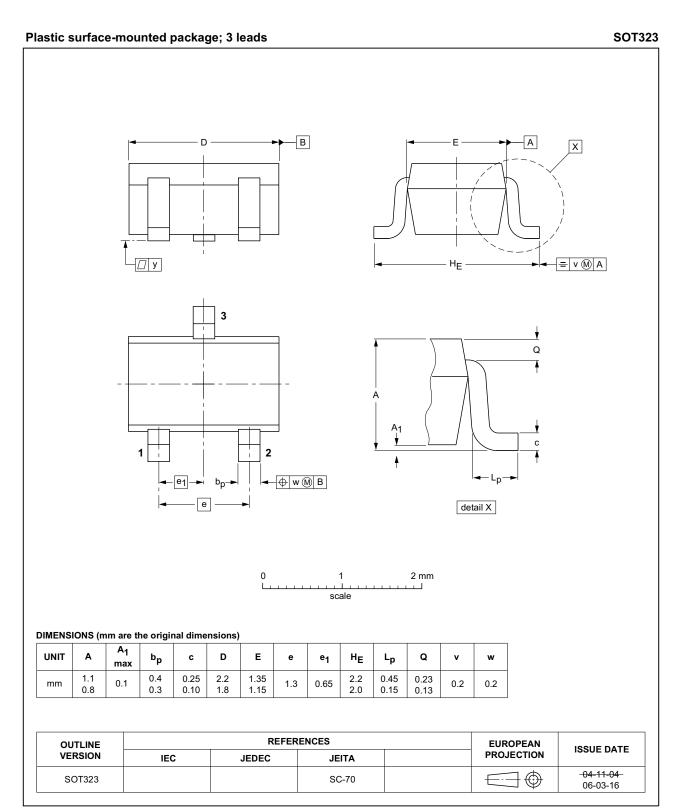


Fig 6. Package outline SOT323

## 9. Abbreviations

Table 8. Abbreviations

Acronym	Description
AQL	Acceptable Quality Level
PIN	P-type, Intrinsic, N-type
SMD	Surface Mounted Device
S4	Special inspection level 4

# 10. Revision history

### Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BAP64-05W v.2	20150428	Product data sheet	-	BAP64-05W v.1		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>AEC-Q101 qualified</li> </ul>					
BAP64-05W v.1 (9397 750 07192)	20000713	Product specification	-	-		

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#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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#### Silicon PIN diode

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**BAP64-05W** 

Silicon PIN diode

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